

USBLC6-4

Features

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- 4 data lines protection
- Protects V_{BUS}
- Very low capacitance: 3 pF typ.
- SOT23-6L package
- RoHS compliant

Benefits

- Very low capacitance between lines to GND for optimized data integrity and speed
- Low PCB space consumption, 9 mm² maximum foot print
- Enhanced ESD protection. IEC 61000-4-2 level 4 compliance guaranteed at device level, hence greater immunity at system level
- ESD protection of V_{BUS}. Allows ESD current flowing to Ground when ESD event occurs on data line
- High reliability offered by monolithic integration
- Low leakage current for longer operation of battery powered devices
- Fast response time
- Consistent D+ / D- signal balance:
 - Best capacitance matching tolerance I/O to GND = 0.015 pF
 - Compliant with USB 2.0 requirements < 1 pF

Complies with the following standards

- IEC 61000-4-2 level 4:
 - 15 kV (air discharge)
 - 8 kV (contact discharge)



Very low capacitance ESD protection

Applications

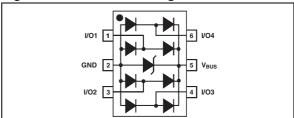
- USB 2.0 ports up to 480 Mb/s (high speed)
- Backwards compatible with USB 1.1 low and full speed
- Ethernet port: 10/100 Mb/s
- SIM card protection
- Video line protection
- Portable electronics

Description

The **USBLC6-4SC6** is a monolithic application specific device dedicated to ESD protection of high speed interfaces, such as USB 2.0, Ethernet links and video lines.

Its very low line capacitance secures a high level of signal integrity without compromising in protecting sensitive chips against the most stringent characterized ESD strikes.

Figure 1. Functional diagram



1 Characteristics

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Table 1. Absolute ratings

Symbol	Parameter		Value	Unit
V _{PP}	Peak pulse voltage	IEC 61000-4-2 air discharge IEC 61000-4-2 contact discharge MIL STD883C-Method 3015-6	15 15 25	kV
T _{stg}	Storage temperature range		-55 to +150	°C
Тj	Operating junction temperature range		-40 to +125	°C
ΤL	Lead solder temperature (10 seconds duration)		260	°C

Table 2.

2. Electrical characteristics ($T_{amb} = 25 \ ^{\circ}C$)

Symbol	Parameter	Test Conditions	Value			l lmit	
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit	
V _{RM}	Reverse stand-off voltage				5	V	
I _{RM}	Leakage current	V _{RM} = 5 V		10	150	nA	
V _{BR}	Breakdown voltage between V _{BUS} and GND	I _R = 1 mA	6			v	
V _F	Forward voltage	l _F = 10 mA			0.86	V	
Max		I _{PP} = 1 A, 8/20 μs Any I/O pin to GND			12	v	
V _{CL}	Clamping voltage	I _{PP} = 5 A, 8/20 μs Any I/O pin to GND			17	v	
C _{i/o-GND}	Capacitance between I/O and GND	V _R = 1.65 V		3	4	nE	
$\Delta C_{i/o-GND}$				0.015		- pF	
C _{i/o-i/o}	Capacitance between I/O	V _R = 1.65 V		1.85	2.7	7 pF	
ΔC _{i/o-i/o}				0.04			



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1000

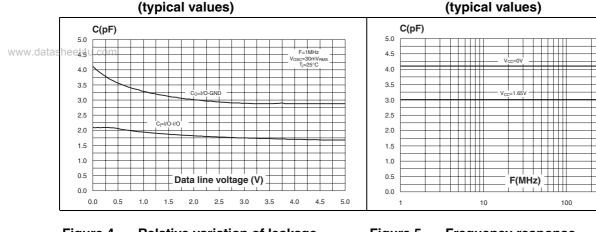
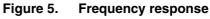


Figure 4. Relative variation of leakage current versus junction temperature (typical values)



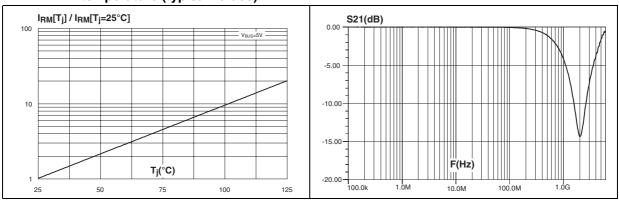


Figure 2. Capacitance versus voltage



2 Technical information

2.1 Surge protection

The USBLC6-4SC6 is particularly optimized to provide surge protection based on the rail to rail topology.

The clamping voltage $V_{\mbox{CL}}$ can be calculated as follows:

 V_{CL} + = $V_{TRANSIL}$ + V_{F} for positive surges

 V_{CL} - = - V_F for negative surges

with: $V_F = V_T + R_d I_p$

(V_F forward drop voltage, V_T forward drop threshold voltage

Calculation example

We assume that the value of the dynamic resistance of the clamping diode is typically:

 $R_d = 0.5 \Omega$ and $V_T = 1.1 V$.

For an IEC 61000-4-2 surge level 4 (Contact Discharge: V_g = 8 kV, R_g = 330 Ω), V_{BUS} = +5 V, and if in a first approximation, we assume that:

$$I_p = V_q / R_q = 24 A.$$

So, we find:

V_{CL}+ = +31.2 V V_{CL}- = -13.1 V

Note:

The calculations do not take into account phenomena due to parasitic inductances.

2.2 Surge protection application example

If we consider that the connections from the pin V_{BUS} to V_{CC}, from from I/O to data line and from GND to PCB GND plane are implemented as racks 10 mm long and 0.5 mm large, we can assume that the parasitic inductances L_{VBUS} L_{I/0} and L_{GND} of these tracks are about 6 nH. So, when an IEC 61000-4-2 surge occurs, due to the rise time of this spike (t_r = 1 ns), the voltage V_{CL} has an extra value equal to L_{I/0}·dI/dt, + L_{GND}·dI/dt

The dl/dt is calculated as:

 $dI/dt = I_p/t_r = 24 \text{ A/ns}$

The overvoltage due to the parasitic inductances is:

 $L_{I/0} \cdot dI/dt$, = $L_{GND} \cdot dI/dt$ = 6 x 24 = 144 V

By taking into account the effect of these parasitic inductances due to unsuitable layout, the clamping voltage will be:

V_{CL}+ = +31.2 + 144 + 144 = 319.2 V V_{CL}- = -13.1 - 144 -144 = -301.1 V

We can significantly reduce this phenomena with simple layout optimization. It is for this reason that some recommendations have to be followed (see *2.3: How to ensure good ESD protection*).

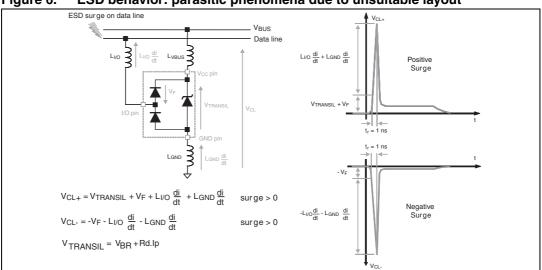
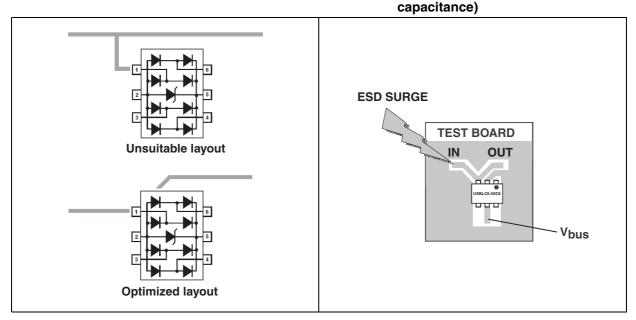


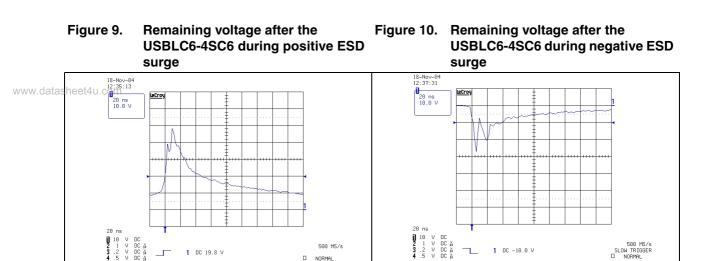
Figure 6. ESD behavior: parasitic phenomena due to unsuitable layout

2.3 How to ensure good ESD protection

While the USBLC6-4SC6 provides high immunity to ESD surge, efficient protection depends on the layout of the board. In the same way, with the rail to rail topology, the track from data lines to I/O pins, from V_{CC} to the V_{BUS} pin and from GND plane to GND pin must be as short as possible to avoid overvoltages due to parasitic phenomena (see Figure 7 and Figure 8 for layout considerations)

Figure 7. ESD behavior: optimized layout and Figure 8. **ESD** behavior: measurement addition of a capacitance of 100 nF conditions (with coupling





NORMAL Note: The measurements have been done with the USBLC6-4SC6 in open circuit.

500 MS/s

Important:

A good precaution to take is to put the protection device as close as possible to the disturbance source (generally the connector).

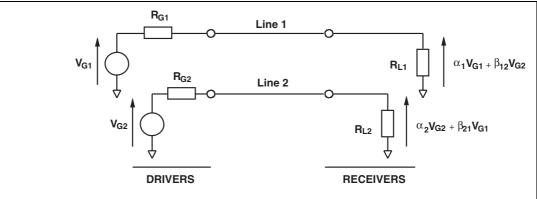
1 DC -10.0 V

2.4 **Crosstalk behavior**

1 DC 19.8 V

2.4.1 Crosstalk phenomenon





The crosstalk phenomenon is due to the coupling between 2 lines. The coupling factor (β 12) or β 21) increases when the gap across lines decreases, particularly in silicon dice. In the above example the expected signal on load R_{L2} is $\alpha_2 V_{G2}$, in fact the real voltage at this point has got an extra value $\beta_{21}V_{G1}.$ This part of the V_{G1} signal represents the effect of the crosstalk phenomenon of the line 1 on the line 2. This phenomenon has to be taken into account when the drivers impose fast digital data or high frequency analog signals in the disturbing line. The perturbed line will be more affected if it works with low voltage signal or high load impedance (few $k\Omega$).



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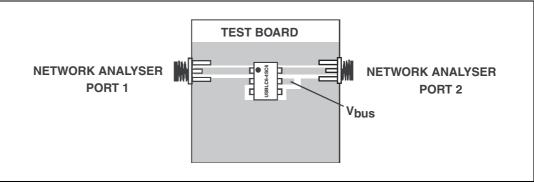
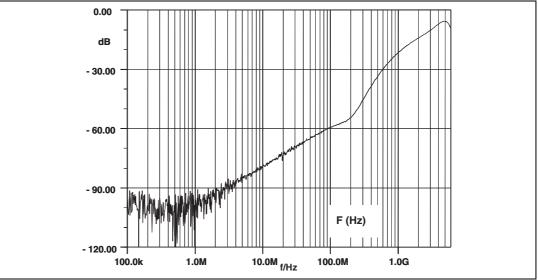


Figure 12. shows the measurement circuit for the analog application. In usual frequency range of analog signals (up to 240 MHz) the effect on disturbed line is less than -55 db (see *Figure 13.*).





As the USBLC6-4SC6 is designed to protect high speed data lines, it must ensure a good transmission of operating signals. The frequency response (*Figure 5.*) gives attenuation information and shows that the USBLC6-4SC6 is well suitable for data line transmission up to 480 Mbit/s while it works as a filter for undesirable signals like GSM (900 MHz) frequencies, for instance.

2.5 Application examples

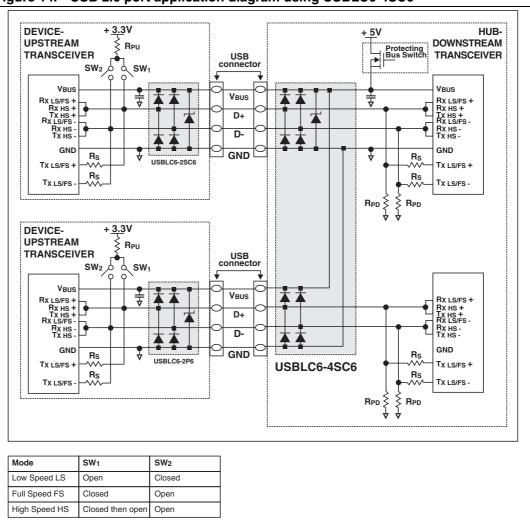
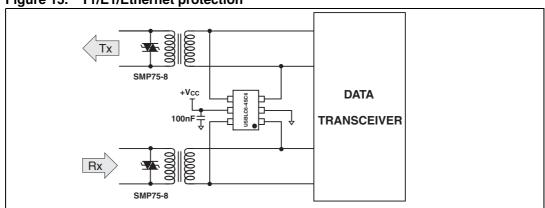


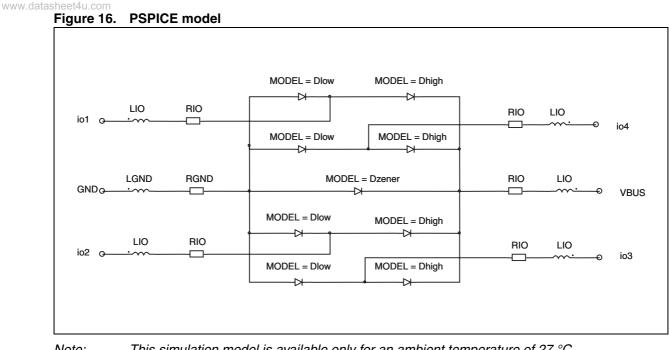
Figure 14. USB 2.0 port application diagram using USBLC6-4SC6

Figure 15. T1/E1/Ethernet protection



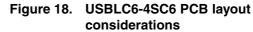
2.6 **PSPICE model**

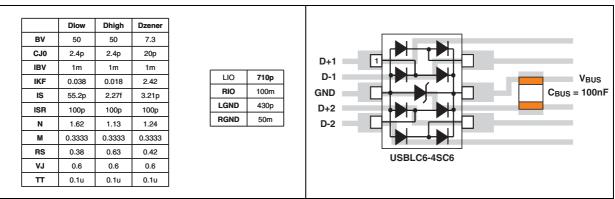
Figure 16. shows the PSPICE model of one USBLC6-4SC6 cell. In this model, the diodes are defined by the PSPICE parameters given in Figure 17.



This simulation model is available only for an ambient temperature of 27 °C. Note:

Figure 17. PSPICE parameters





3 Ordering information scheme

USB LC 6 - 4 SC6
Product Designation
Low capacitance
Breakdown Voltage 6 = 6 Volts
Number of lines protected 4 = 4 lines
Package SC6 = SOT23-6L



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- **Package information**
 - Epoxy meets UL94, V0

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at www.st.com.

Table 3. SOT23-6L dimensions

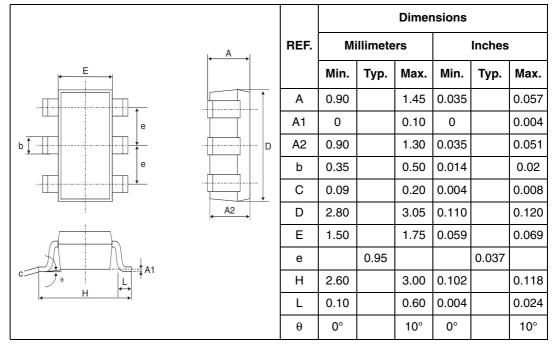
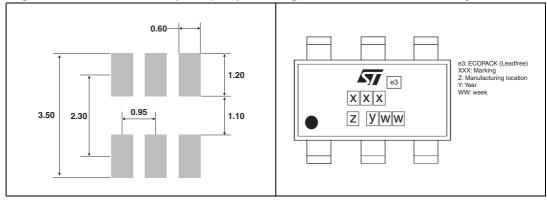


Figure 20. SOT23-6L footprint (mm)

Figure 21. SOT23-6L marking



5 Ordering information

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Table 4.Ordering information

Ordering code	Marking	Package	Weight	Base qty	Delivery mode	
USBLC6-4SC6	UL46	SOT23-6L	16.7 mg	3000	Tape and reel	

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Revision history

Table 5.Document revision history

Date	Revision	Description of changes	
10-Dec-2004	1	First issue.	
28-Feb-2005	2	Minor layout update. No content change.	
04-Feb-2008 3		Updated operating junction temperature range in absolute ratings, page 2. Updated <i>Section 2: Technical information</i> . Updated marking illustration <i>Figure 21</i> . Reformatted to current standard.	



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